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INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary)				Complete if Known	
				Application Number	10/780,526
				Filing Date	February 17, 2004
				First Named Inventor	Milan Pophristic
				Art Unit	2811
Examiner Name	Not Yet Assigned				
Sheet	1	of	1	Attorney Docket Number	EMCORE 3.0-084

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No.†	Document Number	Publication Date	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code* (if known)	MM-DD-YYYY		
	AA	US-2003/141518-A1	07-31-2003	Yokogawa et al.	
	AB	US-5,296,395	03-22-1994	Khan et al.	
	AC	US-6,653,215-B1	11-25-2003	Brown et al.	

FOREIGN PATENT DOCUMENTS						
Examiner Initials*	Cite No.†	Foreign Patent Document	Publication Date	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T*
		Country Code* -Number* -Kind Code* (if known)	MM-DD-YYYY			
	BA	EP-1 189 287-A	03-20-2002	Matsushita Electric Industrial Co., Ltd.		
	BB	WO-03/026021-A	03-27-2003	Cree Lighting Company		

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. †Applicant's unique citation designation number (optional). ‡See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. §Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ¶For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. **Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ***Applicant is to place a check mark here if English language Translation is attached.

NON PATENT LITERATURE DOCUMENTS					
Examiner Initials*	Cite No.†	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.			T*
	CA	"High barrier height GaN Schottky diodes: PVGa _N and Pd/GaN" APPLIED PHYSICS LETTERS, AMERICAN INSTITUTE OF PHYSICS, New York, US, vol. 68 no. 9, 2-26-96; pp. 1267-1269 Feb 25 / 1996			
	CB	Lin Yow-Jon et al: "Nitrogen-vacancy-related defects and Fermi level pinning in n-GaN Schottky diodes" 8/1/03, JOURNAL OF APPLIED PHYSICS, AMERICAN INSTITUTE OF PHYSICS, New York, US, pp. 1819-1822. August 1 / 2003			

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